# Low Leakage Trench-based Schottky Rectifier

# **Exceptionally Low Leakage**

#### **Features**

- Fine Lithography Trench-based Schottky Technology for Low Forward Voltage and Very Low Leakage
- Fast Switching with Exceptional Temperature Stability
- Low Power Loss and Lower Operating Temperature
- Higher Efficiency for Achieving Regulatory Compliance
- Low Thermal Resistance
- High Surge Capability
- These Devices are Pb–Free, Halogen Free/BFR Free and are RoHS Compliant

## **Typical Applications**

- Switching Power Supplies including Notebook / Netbook Adapters, ATX and Flat Panel Display
- High Frequency and DC-DC Converters
- Freewheeling and OR-ing diodes
- Reverse Battery Protection
- Instrumentation

## **Mechanical Characteristics**

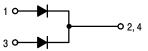
- Case: Epoxy, Molded
- Epoxy Meets Flammability Rating UL 94-0 @ 0.125 in
- Finish: All External Surfaces Corrosion Resistant and Terminal Leads are Readily Solderable
- Lead Temperature for Soldering Purposes: 260°C Maximum for 10 sec

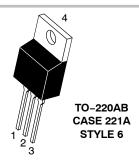


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## PIN CONNECTIONS





## **MARKING DIAGRAM**



TSV20H12EG = Specific Device Code

A = Assembly Location

Y = Year WW = Work Week AKA = Polarity Designator G = Pb-Free Package

## **ORDERING INFORMATION**

See detailed ordering and shipping information on page 2 of this data sheet.

## **MAXIMUM RATINGS**

Rating		Symbol	Value	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage		V <sub>RRM</sub> V <sub>RWM</sub> V <sub>R</sub>	120	V
Average Rectified Forward Current (Rated $V_R$ , $T_C$ = 124°C) (Rated $V_R$ , $T_C$ = 139°C)	Per device Per diode	I <sub>F(AV)</sub>	20 10	Α
Peak Repetitive Forward Current (Rated $V_R$ , Square Wave, 20 kHz, $T_C$ = 122°C) (Rated $V_R$ , Square Wave, 20 kHz, $T_C$ = 137°C)	Per device Per diode	I <sub>FRM</sub>	40 20	Α
Nonrepetitive Peak Surge Current (Surge applied at rated load conditions halfwave, single phase, 60 Hz)		I <sub>FSM</sub>	125	А
Operating Junction Temperature		TJ	-40 to +175	°C
Storage Temperature		T <sub>stg</sub>	-40 to +175	°C

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

#### THERMAL CHARACTERISTICS

Rating		nbol	Value	Unit
1 71	$\begin{array}{c} \text{ion-to-Case} &  &  &  &  &  &  &  &  &  & $		1.7 50	°C/W °C/W

## **ELECTRICAL CHARACTERISTICS** (Per Leg unless otherwise noted)

Rating	Symbol	Тур	Max	Unit
Maximum Instantaneous Forward Voltage (Note 1)	٧ <sub>F</sub>			V
$(I_F = 5 \text{ A}, T_J = 25^{\circ}\text{C})$		0.692	-	
$(I_F = 10 \text{ A}, T_J = 25^{\circ}\text{C})$		0.89	1.0	
$(I_F = 5 \text{ A}, T_J = 125^{\circ}\text{C})$		0.564	_	
(I <sub>F</sub> = 10 A, T <sub>J</sub> = 125°C)		0.652	0.71	
Maximum Instantaneous Reverse Current (Note 1)	I <sub>R</sub>			
$(V_R = 90 \text{ V}, T_J = 25^{\circ}\text{C})$		0.89	-	μΑ
$(V_R = 90 \text{ V}, T_J = 125^{\circ}\text{C})$		1.5	_	mA
(Rated dc Voltage, T <sub>J</sub> = 25°C)		2.0	25	μΑ
(Rated dc Voltage, T <sub>J</sub> = 125°C)		2.4	12	mA

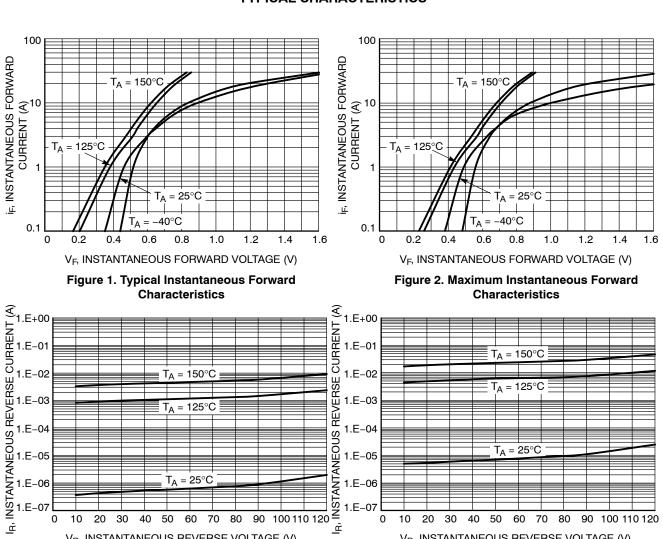
Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

## **ORDERING INFORMATION**

Device	Package	Shipping
NTSV20H120ECTG	TO-220AB (Pb-Free)	50 Units / Rail

<sup>1.</sup> Pulse Test: Pulse Width = 300 μs, Duty Cycle ≤ 2.0%

## **TYPICAL CHARACTERISTICS**



1.E-05

1.E-06 .F-07

'n.

 $T_A = 25^{\circ}C$ 

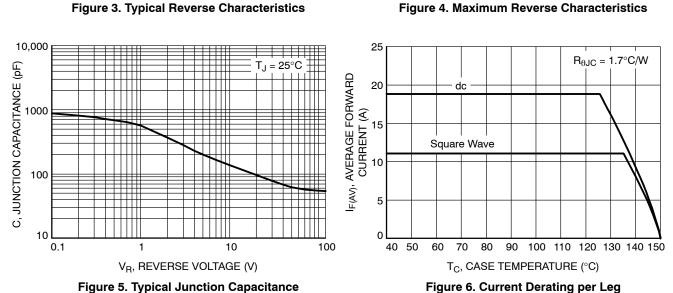
V<sub>R</sub>, INSTANTANEOUS REVERSE VOLTAGE (V)

40 50 60 70 80 90

V<sub>R</sub>, INSTANTANEOUS REVERSE VOLTAGE (V) Figure 3. Typical Reverse Characteristics

40 50 60 70

 $T_A = 25^{\circ}C$ 



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## **TYPICAL CHARACTERISTICS**

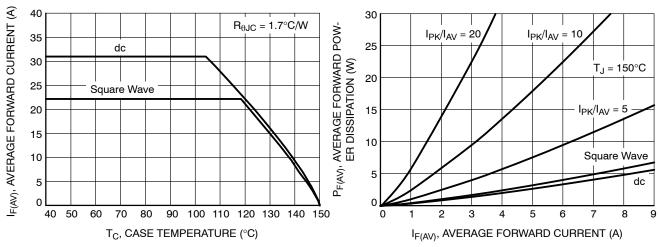


Figure 7. Current Derating, Device

Figure 8. Forward Power Dissipation

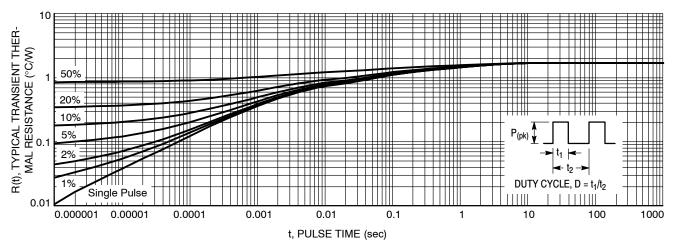
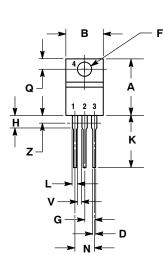
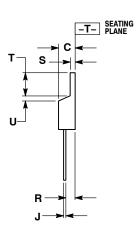


Figure 9. Typical Transient Thermal Response

#### PACKAGE DIMENSIONS

TO-220 CASE 221A-09 **ISSUE AH** 





#### NOTES:

- DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
  CONTROLLING DIMENSION: INCH.
- DIMENSION Z DEFINES A ZONE WHERE ALL BODY AND LEAD IRREGULARITIES ARE ALLOWED.

	INCHES		MILLIMETERS		
DIM	MIN	MAX	MIN	MAX	
Α	0.570	0.620	14.48	15.75	
В	0.380	0.415	9.66	10.53	
С	0.160	0.190	4.07	4.83	
D	0.025	0.038	0.64	0.96	
F	0.142	0.161	3.61	4.09	
G	0.095	0.105	2.42	2.66	
Н	0.110	0.161	2.80	4.10	
Ĺ	0.014	0.024	0.36	0.61	
K	0.500	0.562	12.70	14.27	
L	0.045	0.060	1.15	1.52	
N	0.190	0.210	4.83	5.33	
Q	0.100	0.120	2.54	3.04	
R	0.080	0.110	2.04	2.79	
S	0.045	0.055	1.15	1.39	
Т	0.235	0.255	5.97	6.47	
U	0.000	0.050	0.00	1.27	
٧	0.045	-	1.15		
Z		0.080		2.04	

## STYLE 6:

PIN 1.

- ANODE CATHODE 2.
- ANODE
- CATHODE

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